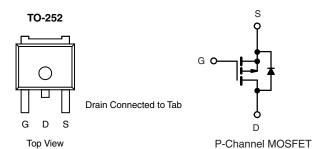


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Vishay Siliconix

Automotive P-Channel 30 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	- 30			
$R_{DS(on)}(\Omega)$ at $V_{GS} = -10 \text{ V}$	0.010			
$R_{DS(on)}(\Omega)$ at $V_{GS} = -4.5 \text{ V}$	0.024			
I _D (A)	- 50			
Configuration	Single			



FEATURES

- TrenchFET® Power MOSFET
- · Package with Low Thermal Resistance
- AEC-Q101 Qualifiedd
- 100 % R_a and UIS Tested
- Material categorization:
 For definitions of compliance please see www.vishay.com/doc?99912



RoHS COMPLIANT HALOGEN FREE

ORDERING INFORMATION	
Package	TO-252
Lead (Pb)-free and Halogen-free	SQD45P03-12-GE3

ABSOLUTE MAXIMUM RATING	S (T _C = 25 °C, unles	s otherwise noted	(k	
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V_{DS}	- 30	V
Gate-Source Voltage		V _{GS}	± 20	
Continuous Drain Current	T _C = 25 °C ^a	1_	- 50	
	T _C = 125 °C		- 37	
Continuous Source Current (Diode Conduction) ^a		I _S	- 50	Α
Pulsed Drain Current ^b		I _{DM}	- 200	
Single Pulse Avalanche Current	. 0.4	I _{AS}	- 31	
Single Pulse Avalanche Energy	L = 0.1 mH	E _{AS}	48	mJ
Maximum Power Dissipation ^b	T _C = 25 °C	T _C = 25 °C	71	W
	T _C = 125 °C	P_{D}	23	VV
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to + 175	°C

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-Ambient P	CB Mount ^c	R _{thJA}	50	°C/W	
Junction-to-Case (Drain)		R _{thJC}	2.1	- C/W	

Notes

- a. Package limited.
- b. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%.$
- c. When mounted on 1" square PCB (FR-4 material).
- d. Parametric verification ongoing.



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static		-						
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} = 0, I _D = - 250 μA		- 30	-	-	V	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}, I_D = -250 \mu A$		- 2.0	- 2.5	V	
Gate-Source Leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = - 30 V	1	-	- 1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = -30 \text{ V}, T_{J} = 125 ^{\circ}\text{C}$	1	-	- 50	μΑ	
		$V_{GS} = 0 V$	$V_{DS} = -30 \text{ V}, T_{J} = 175 ^{\circ}\text{C}$	1	-	- 150	1	
On-State Drain Current ^a	I _{D(on)}	V _{GS} = - 10 V	$V_{DS} \le -5 V$	- 50	-	-	Α	
		V _{GS} = - 10 V	I _D = - 15 A	-	0.008	0.010	- Ω	
Drain-Source On-State Resistance ^a	В	V _{GS} = - 10 V	I _D = - 15 A, T _J = 125 °C	-	-	0.015		
Dialii-Source Oii-State nesistance	R _{DS(on)}	V _{GS} = - 10 V	I _D = - 15 A, T _J = 175 °C	-	-	0.017		
		V _{GS} = - 4.5 V	I _D = - 12 A	-	0.019	0.024		
Forward Transconductanceb	9 _{fs}	V _{DS} = - 15 V, I _D = - 17 A		-	34	-	S	
Dynamic ^b								
Input Capacitance	C _{iss}			1	2794	3495		
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = - 15 V, f = 1 MHz	1	616	770	pF	
Reverse Transfer Capacitance	C _{rss}			1	470	590		
Total Gate Charge ^c	Qg			ı	55.3	83		
Gate-Source Charge ^c	Q_{gs}	V _{GS} = - 10 V	$V_{DS} = -15 \text{ V}, I_{D} = -45 \text{ A}$	-	7.3	-	nC	
Gate-Drain Charge ^c	Q_{gd}			-	14	-		
Gate Resistance	R_{g}		f = 1 MHz		2.86	4.50	Ω	
Turn-On Delay Time ^c	t _{d(on)}				11	16.5		
Rise Time ^c	t _r	$V_{DD} = -15 \text{ V}, R_L = 0.33 \Omega$ $I_D \cong -45 \text{ A}, V_{GEN} = -10 \text{ V}, R_g = 1 \Omega$		-	11	16.5	ns	
Turn-Off Delay Time ^c	t _{d(off)}			-	29	43.5		
Fall Time ^c	t _f			-	19	28.5		
Source-Drain Diode Ratings and Chara	acteristics ^b							
Pulsed Current ^a	I _{SM}			-	-	- 200	Α	
Forward Voltage	V_{SD}	$I_F = -40 \text{ A}, V_{GS} = 0$		-	- 0.9	- 1.5	V	

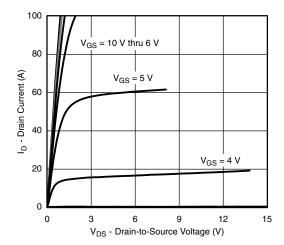
Notes

- a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

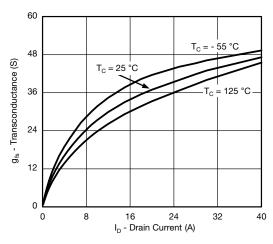
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



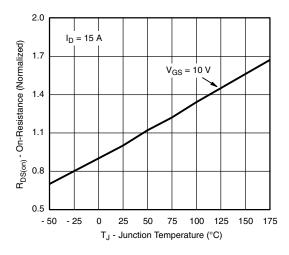
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



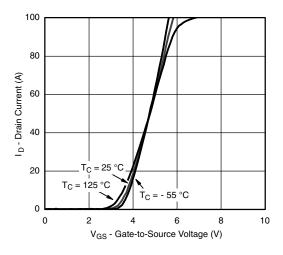
Output Characteristics



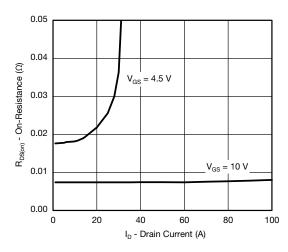
Transconductance



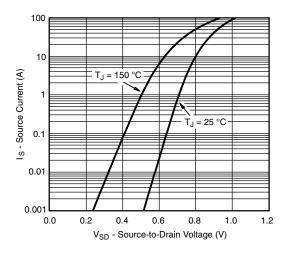
On-Resistance vs. Junction Temperature



Transfer Characteristics



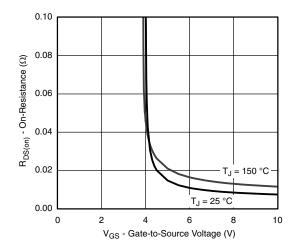
On-Resistance vs. Drain Current



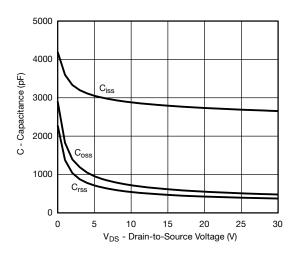
Source Drain Diode Forward Voltage



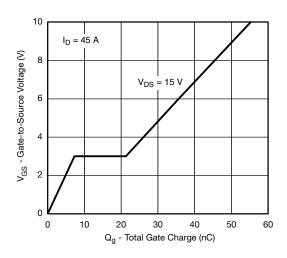
TYPICAL CHARACTERISTICS ($T_A = 25 \, ^{\circ}\text{C}$, unless otherwise noted)



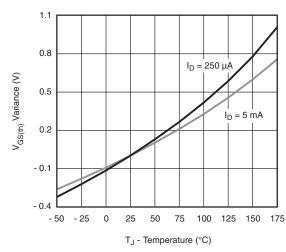
On-Resistance vs. Gate-to-Source Voltage



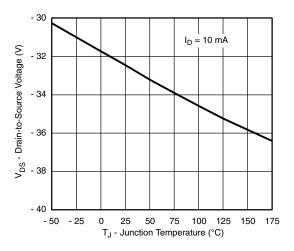
Capacitance



Gate Charge



Threshold Voltage

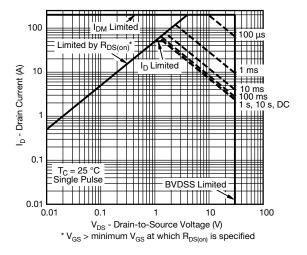


Drain Source Breakdown vs. Junction Temperature

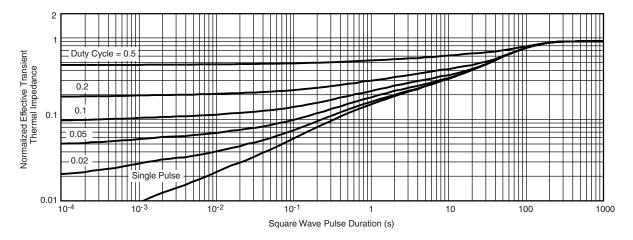
ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



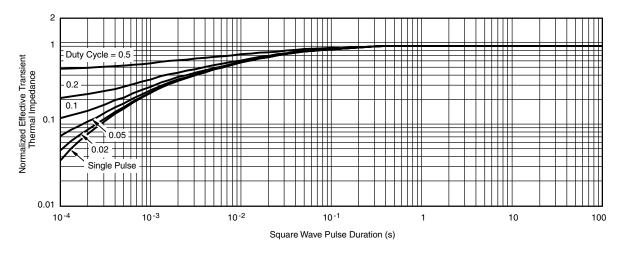
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)

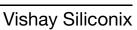


Normalized Thermal Transient Impedance, Junction-to-Case

Note

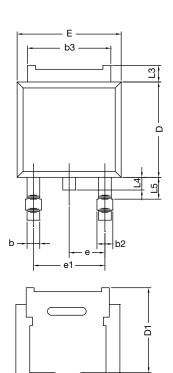
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

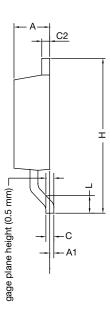
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg265549.





TO-252AA Case Outline





	MILLIN	METERS	INC	HES	
DIM.	MIN.	MAX.	MIN.	MAX.	
Α	2.18	2.38	0.086	0.094	
A1	-	0.127	-	0.005	
b	0.64	0.88	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	
С	0.46	0.61	0.018	0.024	
C2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	
D1	4.10	-	0.161	-	
Е	6.35	6.73	0.250	0.265	
E1	4.32	-	0.170	-	
Н	9.40	10.41	0.370	0.410	
е	2.28	BSC	0.090 BSC		
e1	4.56 BSC		0.180 BSC		
L	1.40	1.78	0.055	0.070	
L3	0.89	1.27	0.035	0.050	
L4	-	1.02	-	0.040	
L5	1.01	1.52	0.040	0.060	
ECN: T13-0592-Rev. A, 02-Sep-13					

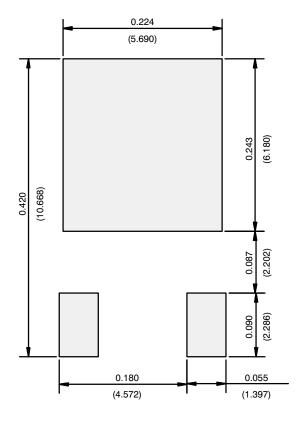
DWG: 6019

Note

• Dimension L3 is for reference only.



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

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